

300MHz Single Supply Video Amplifier with Low In/Out Rail

- **Bandwidth: 300MHz**
- **Single supply operation down to 3V**
- **Low input & output rail**
- **Very low harmonic distortion**
- **Slew rate: 400V/ μ s**
- **Voltage Input noise: 7nV/ $\sqrt{\text{Hz}}$**
- **Specified for 150 Ω load and 100 Ω load**
- **Tested on 5V power supply**
- **Data min. and max. are tested during production (Table 3)**

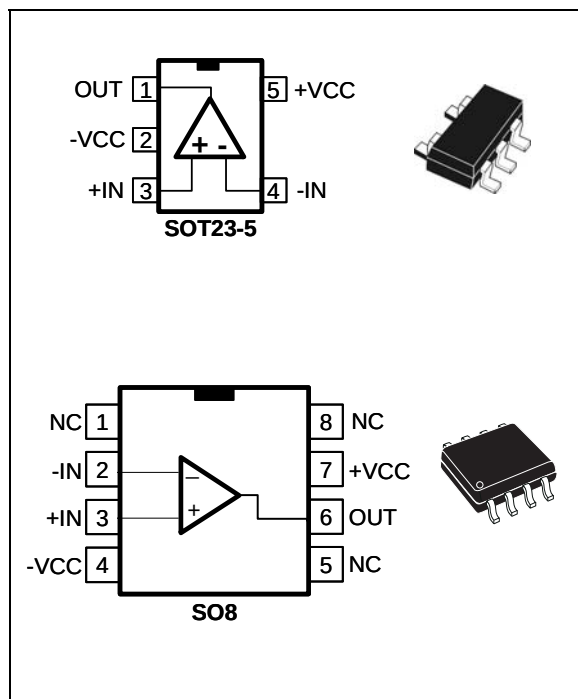
Description

The TSH341 is a single supply operational amplifier featuring a large bandwidth of 300MHz at unity gain for only 9.8mA of quiescent current.

An **advantage** of this circuit is its low input and output rail feature which is very close to GND in single supply. This rail is tested and guaranteed during production at 60mV (max.) from GND on a 150 Ω load. This allows a good output swing which fits perfectly when driving a video signal on a 75 Ω video line. *Chapter 5* gives technical support when using the TSH341 as a driver for video DAC output on a video line. In particular, this chapter focuses on applying a video signal DC shift to avoid any clamping of the synchronization tip.

The TSH341 is available in the tiny SOT23-5 and SO8 plastic packages.

Pin Connections (top view)



Applications

- **High-end video systems**
- **High Definition TV (HDTV)**
- **Broadcast video**
- **Multimedia products**

Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
TSH341ILT	-40°C to +85°C	SOT23-5	Tape & Reel	K307
TSH341ID		SO-8	Tube	H341I
TSH341IDT			Tape & Reel	H341I

1 Absolute Maximum Ratings

Table 1. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}	Supply voltage ¹	6	V
V_{id}	Differential Input Voltage ²	+/-0.5	V
V_{in}	Input Voltage Range ³	-0.2 to +3	V
T_{oper}	Operating Free Air Temperature Range	-40 to +85	°C
T_{std}	Storage Temperature	-65 to +150	°C
T_j	Maximum Junction Temperature	150	°C
R_{thjc}	Thermal Resistance Junction to Case SOT23-5 SO8	80 28	°C/W
R_{thja}	Thermal Resistance Junction to Ambient Area SOT23-5 SO8	250 175	°C/W
$P_{max.}$	Maximum Power Dissipation (@ $T_a=25^{\circ}C$) for $T_j=150^{\circ}C$ SOT23-5 SO8	500 715	mW
ESD	CDM: Charged Device Model	2	kV
	HBM: Human Body Model	1.5	kV
	MM: Machine Model	200	V
	Output Short Circuit	4	

- 1) All voltage values, except differential voltage are with respect to network terminal.
- 2) Differential voltage are non-inverting input terminal with respect to the inverting input terminal.
- 3) The magnitude of input and output voltage must never exceed $V_{CC} + 0.3V$.
- 4) An output current limitation protects the circuit from transient currents. Short-circuits can cause excessive heating. Destructive dissipation can result from short circuit on amplifiers.

Table 2. Operating conditions

Symbol	Parameter	Value	Unit
V_{CC}	Power Supply Voltage	3 to 5.5 ¹	V
V_{icm}	Common Mode Input Voltage	-0.4 to 3	V

- 1) Tested in full production at 0V/5V single power supply

2 Electrical Characteristics

Table 3. $V_{CC} = +5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
DC Performance						
V _{io}	Input Offset Voltage	T _{amb} , V _{icm} =0.6V	-15	-3	15	mV
		-40°C < T _{amb} < +85°C		-5		
ΔV _{io}	V _{io} drift vs. Temperature	-40°C < T _{amb} < +85°C		-30		μV/°C
I _{ib}	Input Bias Current	T _{amb} , V _{icm} =0.6V		6	16	μA
		-40°C < T _{amb} < +85°C		7.2		
A _{VD}	Open Loop Gain	ΔV _{OUT} =2V, R _L =150Ω	70	100		dB
CMR	Common Mode Rejection Ratio 20 log (ΔV _{icm} /ΔV _{io})	ΔV _{icm} = 2V	-60	-85		dB
		-40°C < T _{amb} < +85°C		-83		
SVR	Supply Voltage Rejection Ratio 20 log (ΔV _{cc} /ΔV _{io})	ΔV _{cc} =4V to 5V, V _{icm} =0.6V	-60	-85		dB
		-40°C < T _{amb} < +85°C		-84		
PSR	Power Supply Rejection Ratio 20 log (ΔV _{cc} /ΔV _{out})	ΔV _{cc} =200mVp-p, F=1MHz		-77		dB
R _{IN}	Input Resistance			8.2		MΩ
C _{IN}	Input Capacitance			3.5		pF
ICC	Total Supply Current	No Load, V _{icm} =0.6V		9.8	12.7	mA
Dynamic Performance and Output Characteristics						
Bw	-3dB Bandwidth	Small Signal V _{OUT} =20mVp V _{icm} =0.6V, R _L =150Ω Gain=+1 Gain=+2	90	300 150		MHz
	Gain Flatness @ 0.1dB	Small Signal V _{OUT} =20mVp Gain=+2, V _{icm} =0.6V, R _L =150Ω		65		
FPBW	Full Power Bandwidth	V _{icm} =2V, V _{OUT} = 2Vp-p, Gain=1, R _L = 150Ω	70	100		MHz
SR	Slew Rate	V _{OUT} =2Vp-p, R _L =150Ω, Gain=+2,		400		V/μs
V _{OH}	High Level Output Voltage	R _L = 150Ω	3.7	3.9		V
V _{OL}	Low Level Output Voltage	R _L = 150Ω		40	60	mV
I _{OUT}	Output Short Circuit Current	T _{amb}	70	100		mA
		-40°C < T _{amb} < +85°C		90		
Noise and Distortion						
eN	Equivalent Input Noise Voltage	F = 100kHz		7		nV/√Hz
iN	Equivalent Input Noise Current (+)	F = 100kHz		1.5		pA/√Hz
HD2	2nd Harmonic Distortion	V _{OUT} = 2Vp-p, R _L = 150Ω Gain=+2, F= 10MHz,		-57		dBc
HD3	3rd Harmonic Distortion	V _{OUT} = 2Vp-p, R _L = 150Ω Gain=+2, F= 10MHz,		-63		dBc

Figure 1. Frequency response

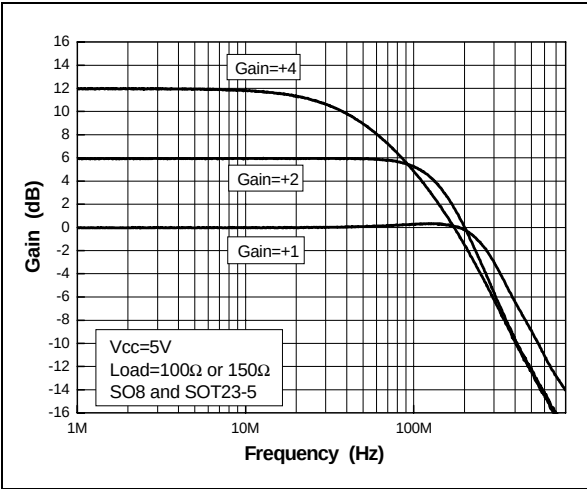


Figure 4. Frequency response on capa-load

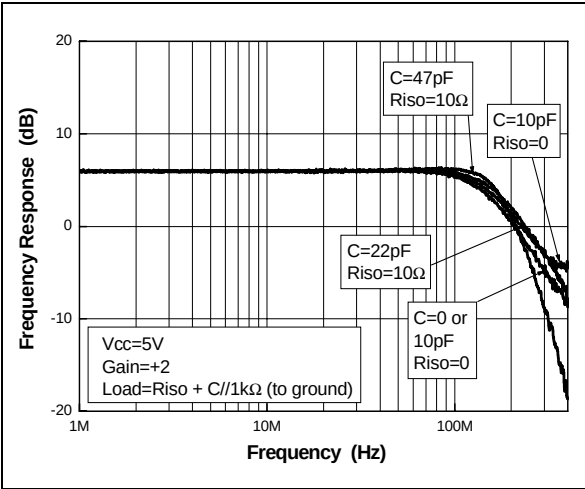


Figure 2. Gain flatness - SOT23-5L

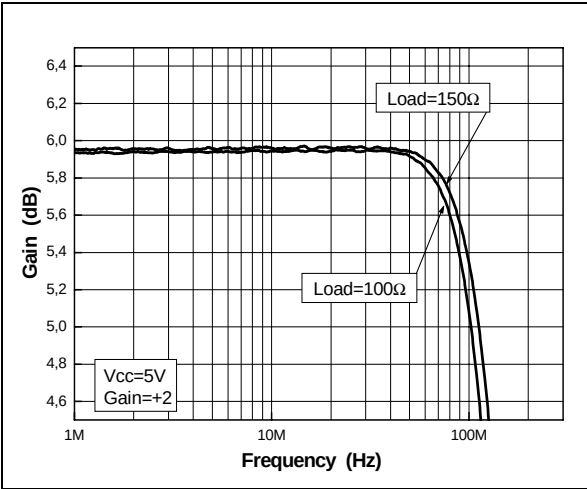


Figure 5. Gain flatness - SO8

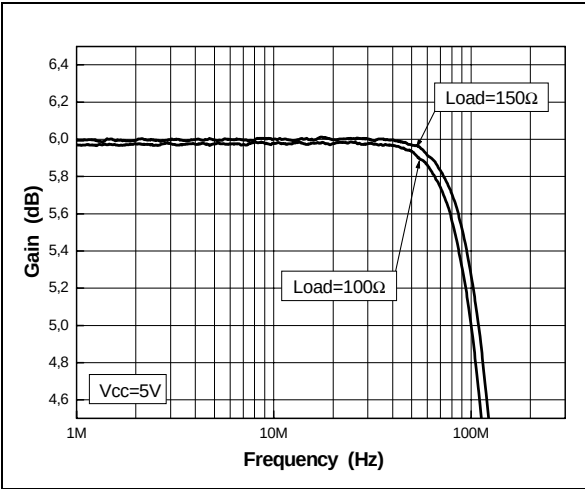


Figure 3. Total input noise vs. frequency

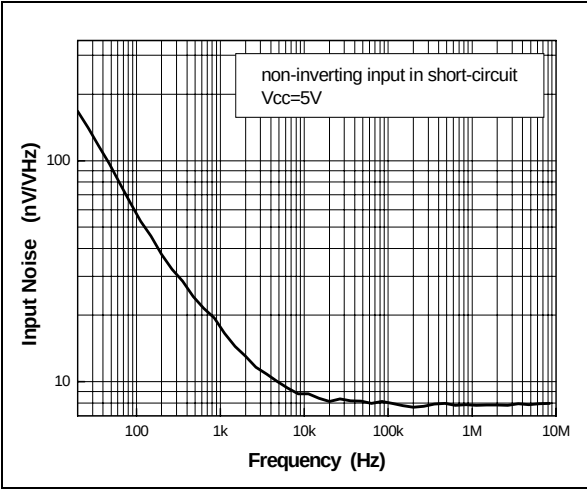


Figure 6. Positive and negative slew rate

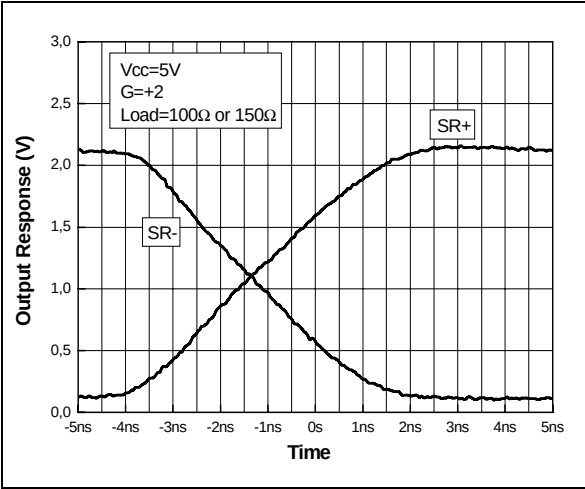


Figure 7. Distortion on 100Ω load

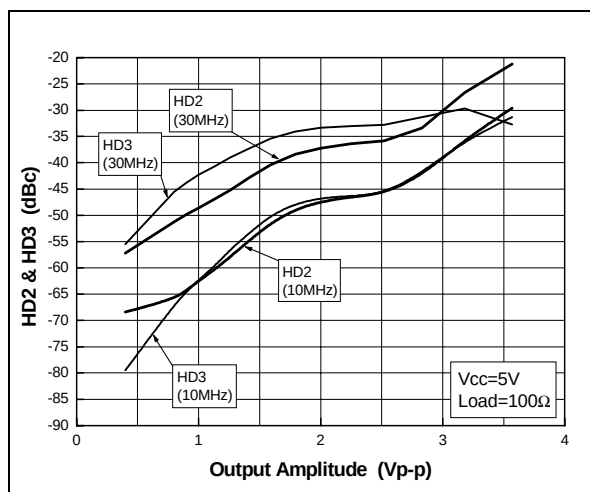


Figure 10. Distortion on 150Ω load

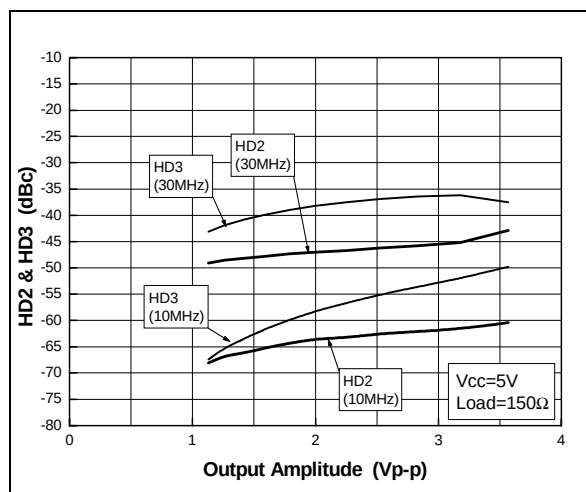


Figure 8. Output lower rail vs. frequency

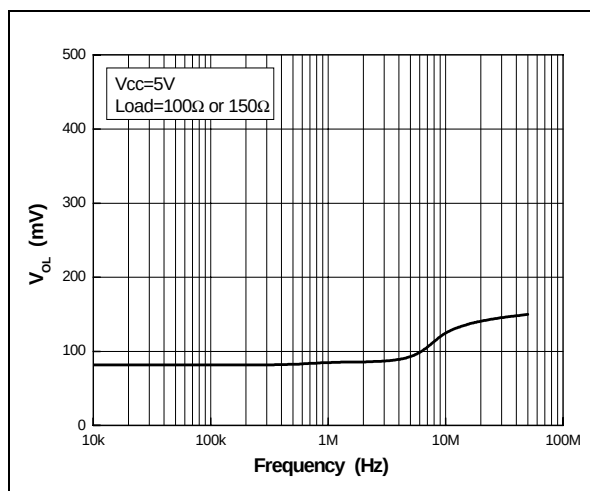


Figure 11. Output voltage swing vs. Vcc

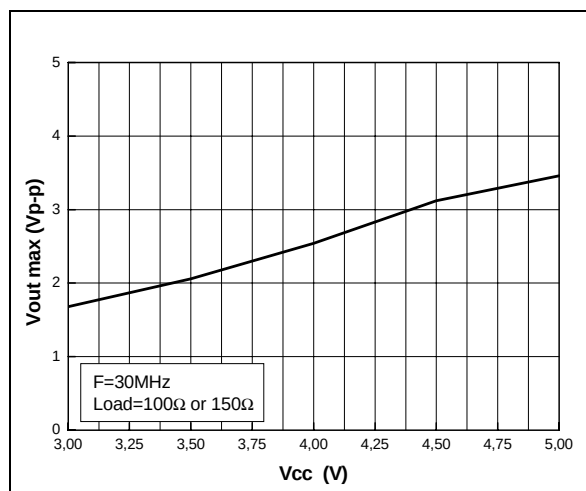


Figure 9. Output voltage swing vs. frequency

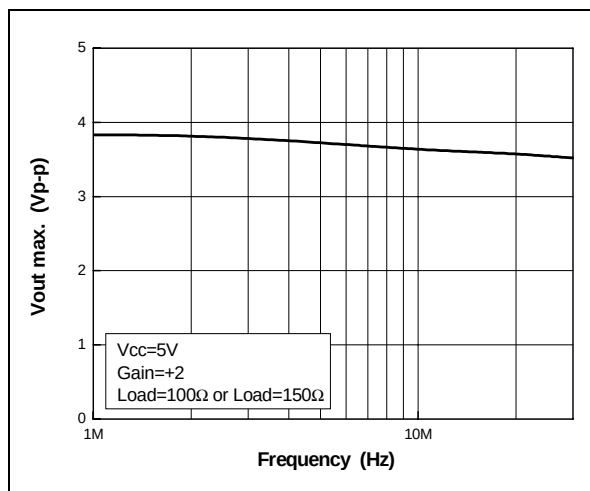


Figure 12. Quiescent current vs. Vcc

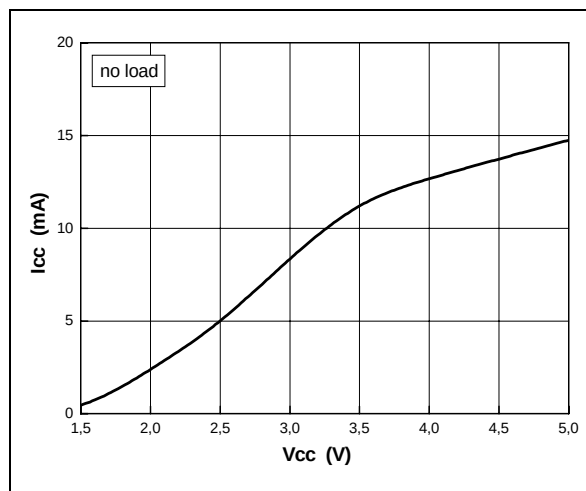


Figure 13. Isource

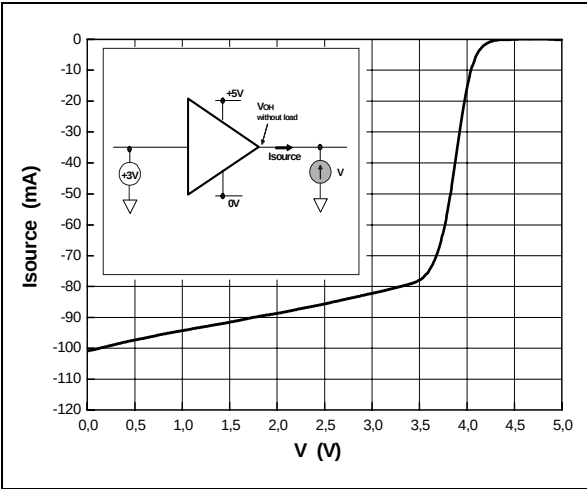


Figure 16. Reverse isolation vs. frequency

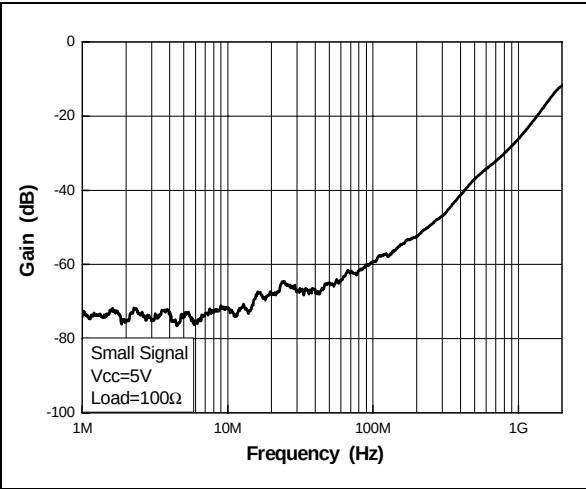


Figure 14. Bandwidth vs. temperature

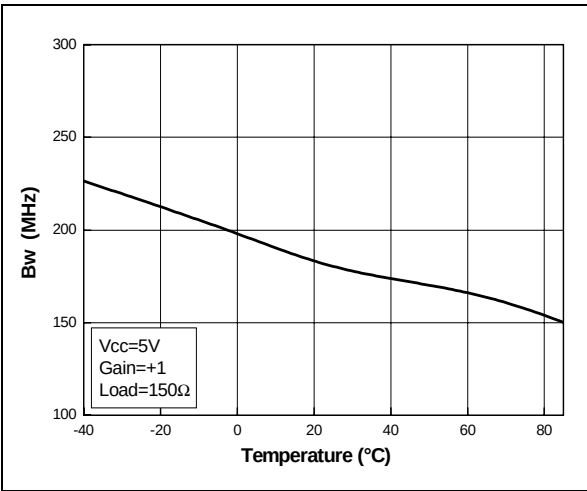


Figure 17. I_{bias} vs. temperature

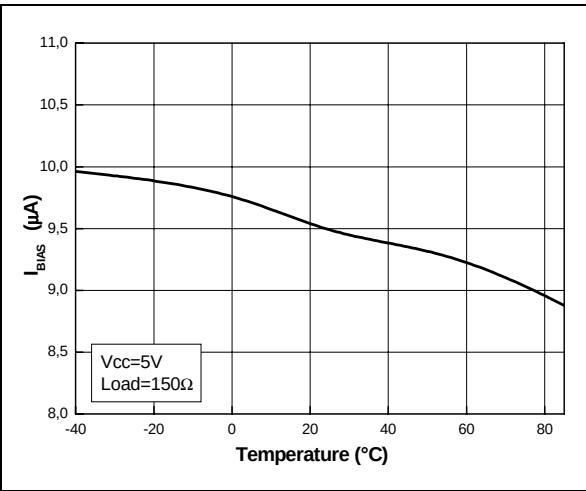


Figure 15. Input offset vs. temperature

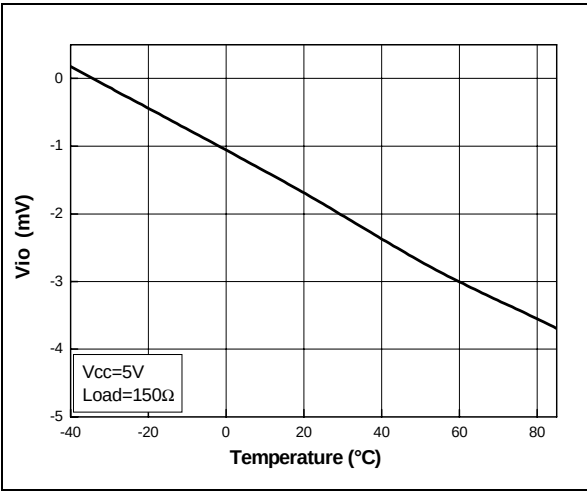


Figure 18. Supply current vs. temperature

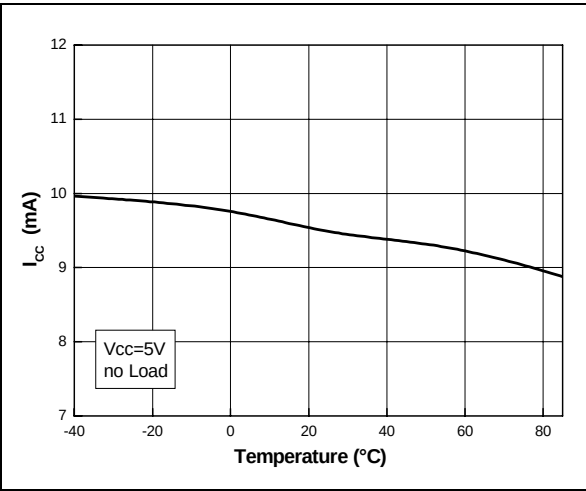


Figure 19. Output lower rail vs. temperature

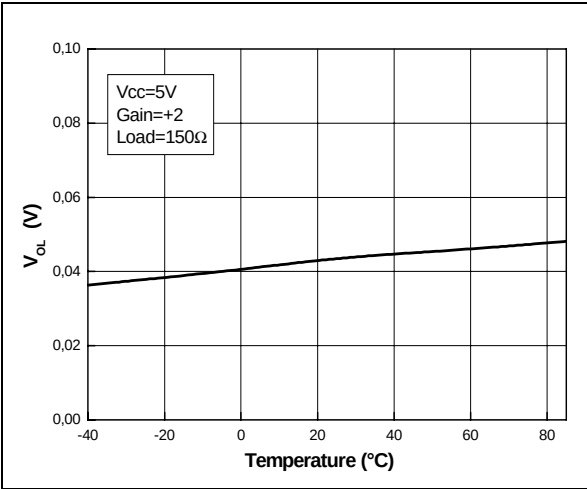


Figure 21. Output higher rail vs. temperature

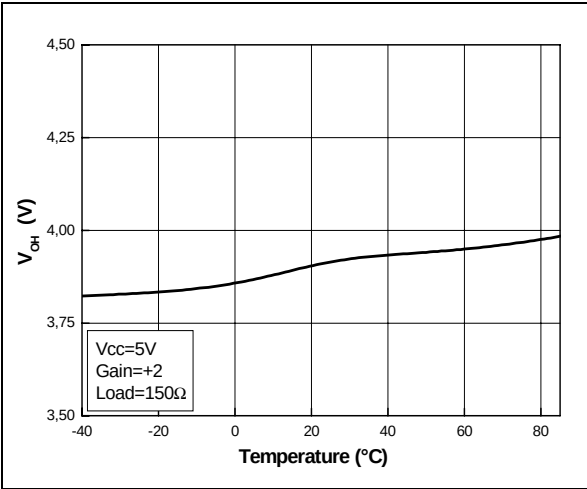


Figure 20. SVR vs. temperature

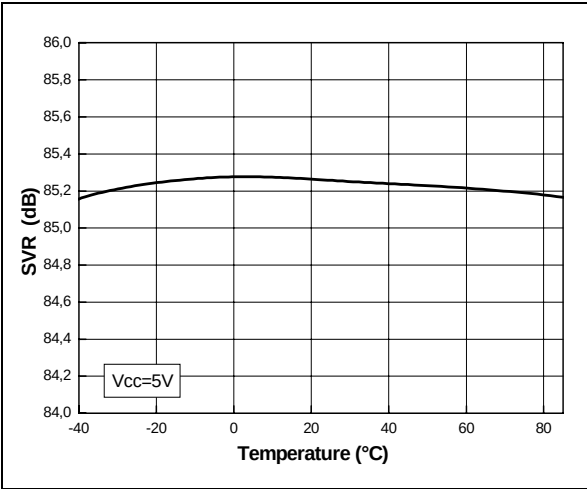
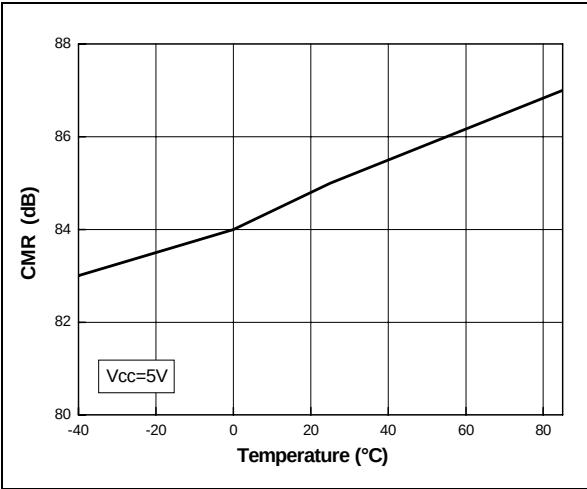


Figure 22. CMR vs. temperature



3 Evaluation Boards

An evaluation board kit optimized for high speed operational amplifiers is available (order code: KITHSEVAL/STD). The kit includes the following evaluation boards, as well as a CD-ROM containing datasheets, articles, application notes and a user manual:

- SOT23_SINGLE_HF BOARD: Board for the evaluation of a single high-speed op-amp in SOT23-5 package.
- SO8_SINGLE_HF: Board for the evaluation of a single high-speed op-amp in SO8 package.
- SO8_DUAL_HF: Board for the evaluation of a dual high-speed op-amp in SO8 package.
- SO8_S_MULTI: Board for the evaluation of a single high-speed op-amp in SO8 package in inverting and non-inverting configuration, dual and single supply.
- SO14_TRIPLE: Board for the evaluation of a triple high-speed op-amp in SO14 package with video application considerations.

Board material:

- 2 layers
- FR4 ($\epsilon_r=4.6$)
- epoxy 1.6mm
- copper thickness: 35 μ m

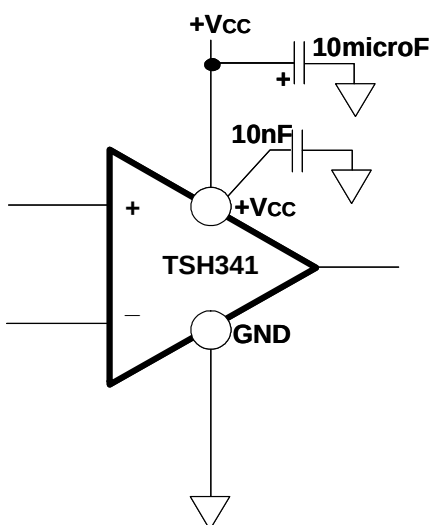
Figure 23: Evaluation kit for high speed op-amps



4 Power Supply Considerations

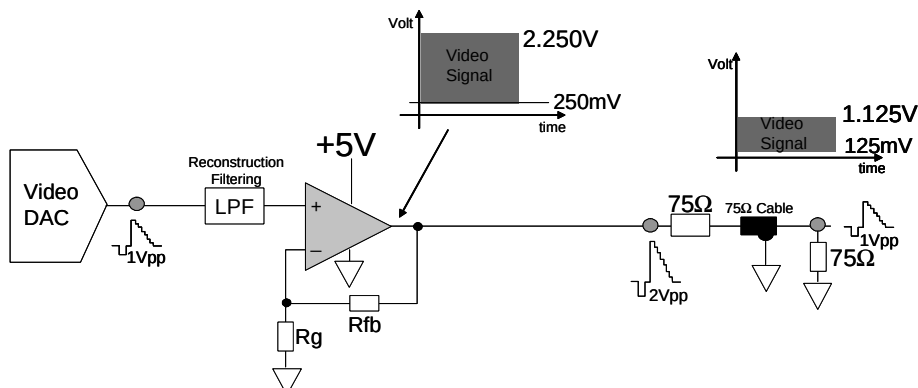
Correct power supply bypassing is very important for optimizing performance in high-frequency ranges. Bypass capacitors should be placed as close as possible to the IC pins to improve high-frequency bypassing. A capacitor greater than $10\mu\text{F}$ is necessary to minimize the distortion. For better quality bypassing, a capacitor of 10nF is added using the same implementation conditions. Bypass capacitors must be incorporated for both the negative and the positive supply. On the SO8_SINGLE_HF board, these capacitors are C8 and C6.

Figure 24: Circuit for power supply bypassing



5 Using the TSH341 to Drive Video Signals

Figure 25. Implementation of the video driver on output video DACs

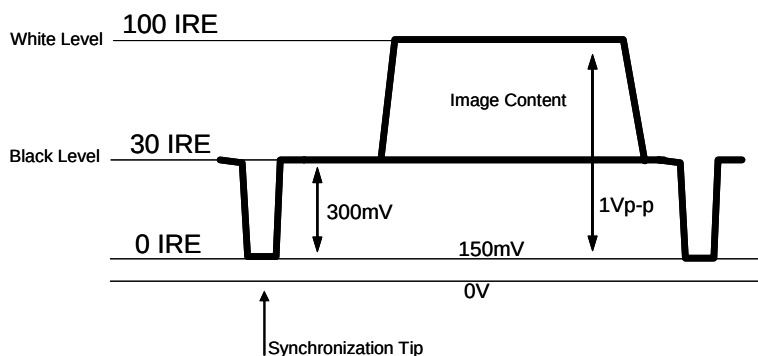


$V_{OL}(50\text{MHz}) = 150\text{mV}$ (Figure 8)

To drive the video signal properly, the output of the driver must be at least equal to 250mV (assuming V_{iO} and V_{OL} variations).

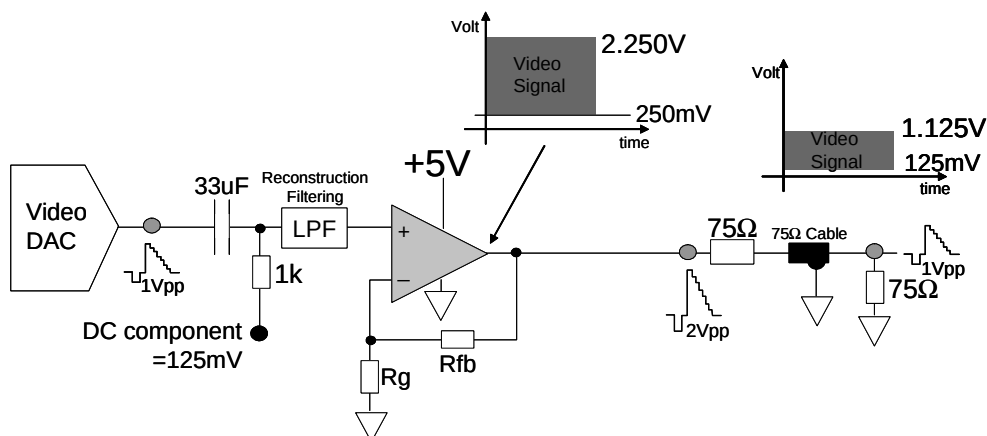
- 1st solution:**

Set the video DAC 0-IRE output level to 125mV.



- 2nd solution:**

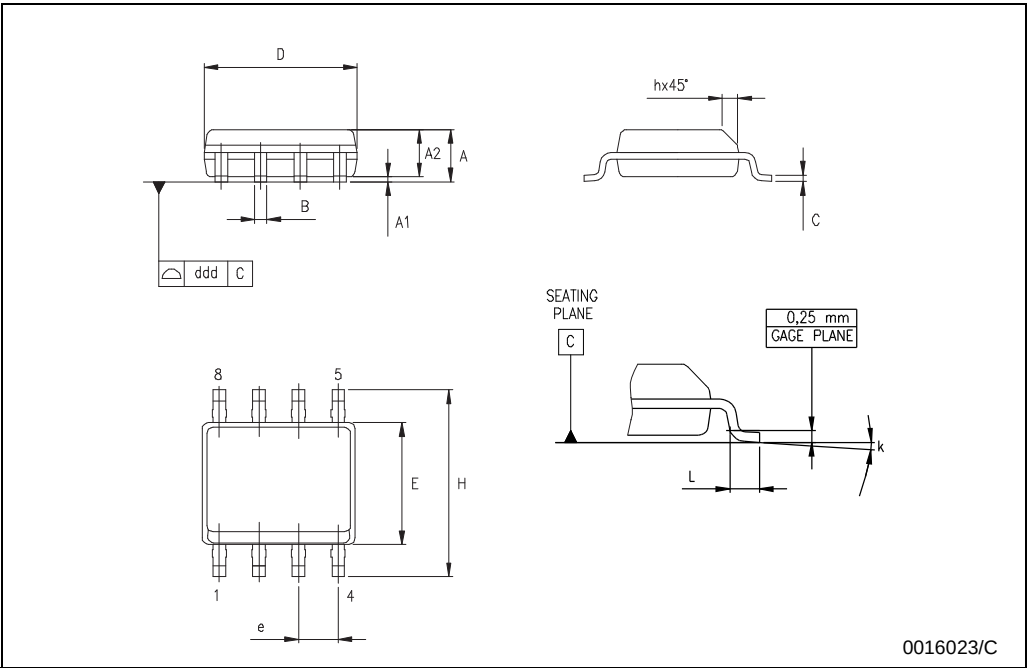
Implementation of a DC component in the input of the driver.



6 Package Mechanical Data

6.1 SO-8 Package

SO-8 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	1.35		1.75	0.053		0.069
A1	0.10		0.25	0.04		0.010
A2	1.10		1.65	0.043		0.065
B	0.33		0.51	0.013		0.020
C	0.19		0.25	0.007		0.010
D	4.80		5.00	0.189		0.197
E	3.80		4.00	0.150		0.157
e		1.27			0.050	
H	5.80		6.20	0.228		0.244
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	8° (max.)					
ddd			0.1			0.04



6.2 SOT23-5L (5-pin) package

SOT23-5L MECHANICAL DATA						
DIM.	mm.			mils		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A	0.90		1.45	35.4		57.1
A1	0.00		0.15	0.0		5.9
A2	0.90		1.30	35.4		51.2
b	0.35		0.50	13.7		19.7
C	0.09		0.20	3.5		7.8
D	2.80		3.00	110.2		118.1
E	2.60		3.00	102.3		118.1
E1	1.50		1.75	59.0		68.8
e		0.95			37.4	
e1		1.9			74.8	
L	0.35		0.55	13.7		21.6

The diagram illustrates the mechanical specifications of the SOT23-5L package. The left view is a side profile showing dimensions A (total width), A1 (lead thickness), A2 (lead length), b (lead thickness at base), C (lead thickness at tip), and L (package height). The right view is a top-down perspective showing dimensions D (package width), E (package length), E1 (package length excluding leads), e (pitch between leads), e1 (total lead pitch), and b (lead thickness at base).

7 Revision History

Date	Revision	Description of Changes
01 Jan. 2005	1	First release corresponding to Preliminary Data version of datasheet.
23 Mar. 2005	2	Datasheet of mature, full-specification product

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